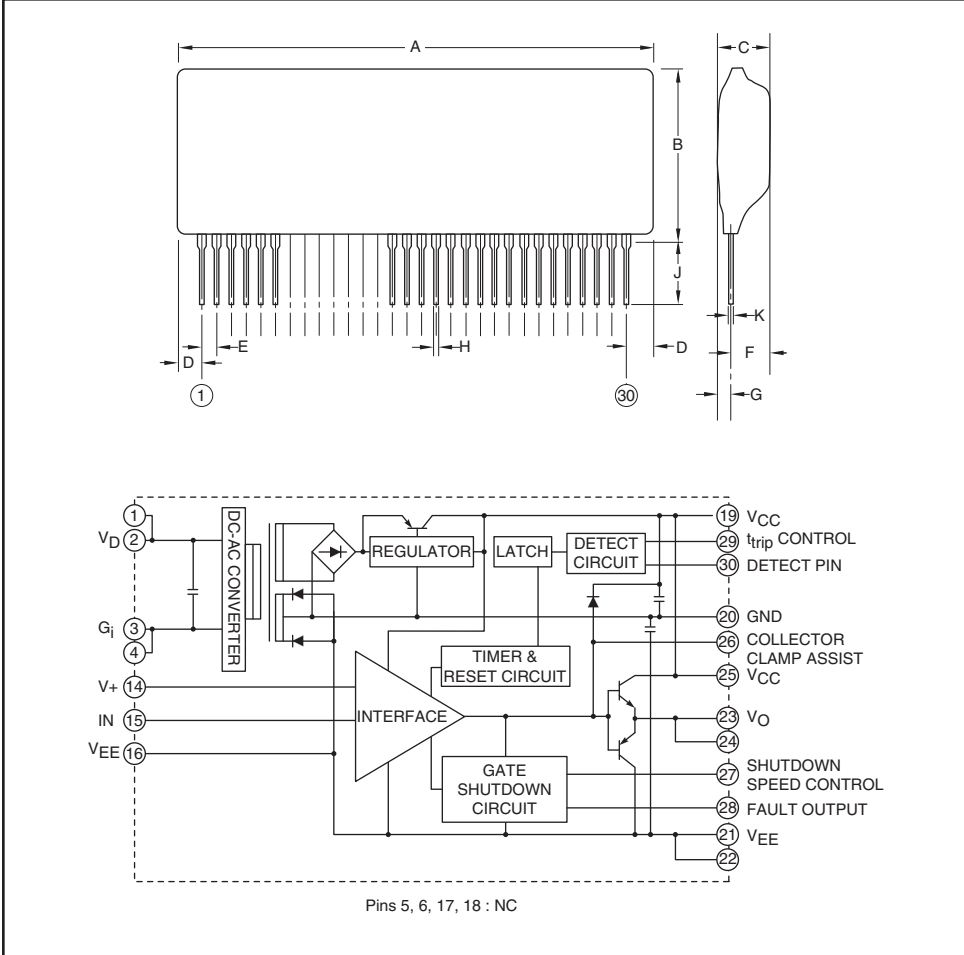
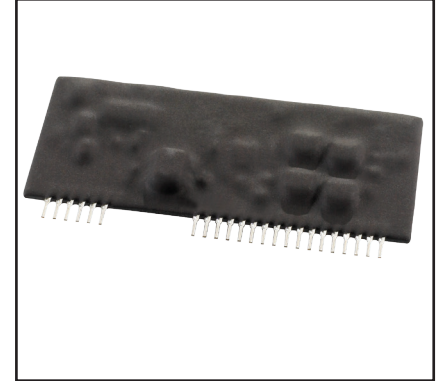


### IGBT Gate Driver + DC/DC Converter



**Circuit Diagram**

Dimensions	Inches	Millimeters
A	3.46 Max.	88.0 Max.
B	1.67 Max.	42.5 Max.
C	0.67 Max.	17.0 Max.
D	0.31 Max.	8.0 Max.
E	0.1	2.54
F	0.45 Max.	11.5 Max.
G	0.24 Max.	6.0 Max.
H	0.03±0.004	0.75±0.1
J	0.14±0.04	3.5±1.0
K	0.028 Max.	0.7 Max.



**Description:**

VLA554-01R is a hybrid integrated circuit designed for driving n-channel IGBT modules in any gate-amplifier application. This device contains a fully isolated DC-DC converter designed to be used with a fiber optic interface for control signal input and fault signal output. The gate driver provides an over-current protection function based on desaturation detection.

**Features:**

- Built in Isolated DC-DC Converter for Gate Drive
- SIP Outline Allows More Space
- Built in Short Circuit Protection with a pin for Fault Output
- Built in Collector Clamp Circuit
- Variable Fall Time on Short-Circuit Protection
- Electrical Isolation Voltage 4000 V<sub>rms</sub> (for 1 Minute)
- CMOS Compatible Input Interface
- Interfaces with Fiber Optic Connector for Isolation of Input Signal

**Applications:**

- To Drive IGBT Modules for General Industrial Use.

**Recommended IGBT Modules:**

V<sub>CES</sub> = 1200V Series up to 3600A Class  
 V<sub>CES</sub> = 1700V Series up to 3600A Class

**VLA554-01R**  
**IGBT Gate Driver + DC/DC Converter**

**Absolute Maximum Ratings,  $T_a = 25^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Rating	Units
Supply Voltage (DC)	$V_D$	-1 ~ 16.5	Volts
Output Voltage ("H" Output Voltage)	$V_O$	$V_{CC}$	Volts
Input Current - Pulse(PW 10msec, Duty Cycle 50%, Applied Pin 1,2)	$I_{IN(PULSE)}$	4	Amperes
Output Current (Pulse Width 3 $\mu$ s)	$I_{OHP}$	-24	Amperes
	$I_{OLP}$	24	Amperes
Isolation Voltage (Sine Wave Voltage 60Hz, for 1 min., R.H. <60%)	$V_{iso}$	4000	$V_{rms}$
Case Temperature (Surface Temperature)	$T_C$	100	$^\circ\text{C}$
Operating Temperature (No Condensation Allowable)	$T_{opr}$	-30 ~ 70	$^\circ\text{C}$
Storage Temperature (No Condensation Allowable)	$T_{stg}$	-40 ~ 100 <sup>*1</sup>	$^\circ\text{C}$
Fault Output Current (Applied at Pin 28)	$I_{FO}$	20	mA
Input Voltage to Pin 30 (Applied at Pin 30)	$V_{R30}$	60	Volts
Gate Drive Current (Gate Average Current)	$I_{drive}$	210 <sup>*2</sup>	mA

**Electrical Characteristics,  $T_a = 25^\circ\text{C}$ ,  $V_D = 15\text{V}$ ,  $R_G = 1\Omega$ ,  $C_L = 1.6\mu\text{F}$ ,  $f = 3\text{kHz}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Supply Voltage	$V_D$	Recommended Range	14.2	15	15.8	Volts
Switching Frequency	$f$	Recommended Range	—	—	10	kHz
Gate Resistance	$R_G$	Recommended Range	0.33	—	—	$\Omega$
Gate Positive Supply Voltage	$V_{CC}$		15.2	16.5	17.5	Volts
Gate Negative Supply Voltage	$V_{EE}$		-6	-8	-11.5	Volts
Gate Supply Efficiency	$\eta$	Load Current = 210mA, $\eta = (V_{CC} +  V_{EE} ) \times 0.21 / (15 \times I_D) \times 100$	60	72	—	%
"H" Output Voltage	$V_{OH}$	10k $\Omega$ Connected Between Pins 23-20	14	15.3	16.5	Volts
"L" Output Voltage	$V_{OL}$	10k $\Omega$ Connected Between Pins 23-20	-5.5	-7	-11	Volts
"L-H" Propagation Time	$t_{PLH}$	$I_{IH} = 30\text{mA}^{*3}$ , Propagation Time from Pin 15	0.3	0.5	1.0	$\mu\text{s}$
"L-H" Rise Time	$t_r$	$I_{IH} = 30\text{mA}^{*3}$	—	0.6	1.2	$\mu\text{s}$
"H-L" Propagation Time	$t_{PHL}$	$I_{IH} = 30\text{mA}^{*3}$ , Propagation Time from Pin 15	0.2	0.4	1.0	$\mu\text{s}$
"H-L" Fall Time	$t_f$	$I_{IH} = 30\text{mA}^{*3}$	—	0.3	1.2	$\mu\text{s}$
Timer	$t_{timer}$	Between Start and Cancel (Under Input Sign "OFF")	1	—	2	ms
Fault Output Current	$I_{FO}$	Applied Pin 28, $R = 2.4\text{k}\Omega$	—	10	—	mA
Controlled Time Detect Short Circuit 1	$t_{trip1}$	Pin 30: 15V and more, Pin 29: Open	—	3.5	—	$\mu\text{s}$
Controlled Time Detect Short Circuit 2 <sup>*4</sup>	$t_{trip2}$	Pin 30: 15V and more, Pins 29-21, 22: 10pF (Connective Capacitance)	—	3.9	—	$\mu\text{s}$
SC Detect Voltage	$V_{SC}$	Collector Voltage of IGBT	15	—	—	Volts

\*1 Differs from H/C condition.

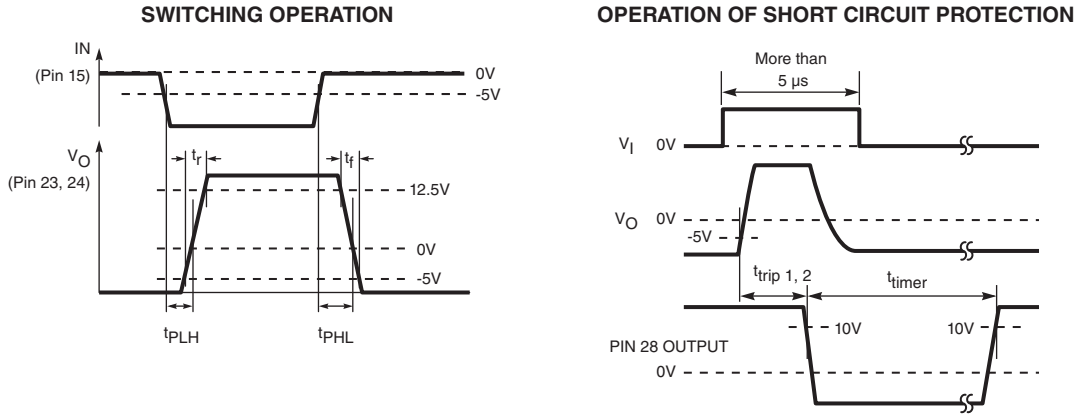
\*2 Refer to  $I_{drive}$ - $T_a$  characteristics.

\*3  $I_{IH}$  is the current which flows through the LED in the optical link of the input interface. Refer to the Measurement Circuit schematic on page 3.

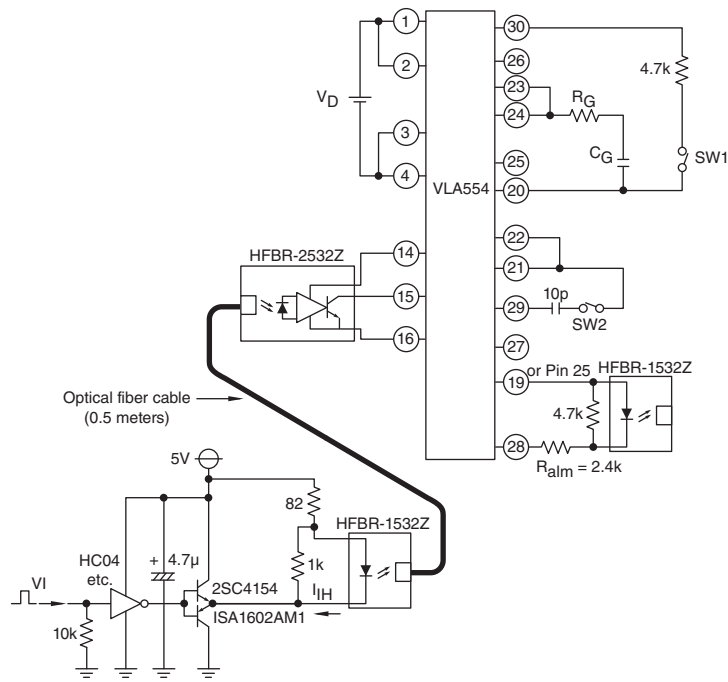
\*4 Length of wiring of capacitor controlled time detect short-circuit is within 5cm from Pins 21, 22 and 29 coming and going.

**VLA554-01R**  
**IGBT Gate Driver + DC/DC Converter**

**Definition of Characteristics**



**Measurement Circuit**

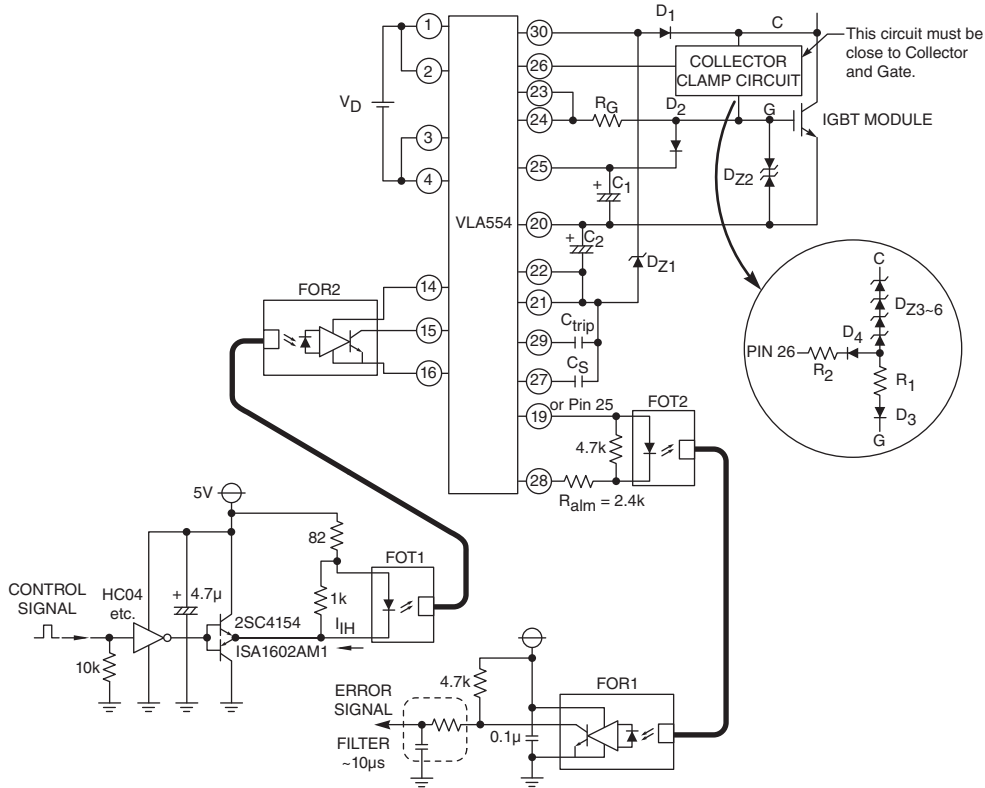


**MEASUREMENT CONDITIONS**

- |                          |  |
|--------------------------|--|
| $T_a = 25^\circ\text{C}$ | SW1 : ON → Switching Mode              |
| $V_D = 15\text{V}$       | SW1 : OFF → Short Circuit Protect Mode |
| $R_G = 1\Omega$          | SW2 : OFF → Measurement of $t_{trip1}$ |
| $C_G = 1.6\mu\text{F}$   | SW2 : ON → Measurement of $t_{trip2}$  |

**VLA554-01R**  
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**Application Example**



$V_D = 15V \pm 5\%$   
 FOT1,2 : HFBR-1532Z (AVAGO) etc.  
 FOR1,2 : HFBR-2532Z (AVAGO) etc.  
 $C_{trip}$  : Depends on  $R_G$   
 $C_S$  : Depends on Surge Voltage  
 $D_{Z1}$  : 30V, 0.5W-1W  
 $D_{Z2}$  : 18V, Bidirectional  
 $D_1$  : Fast Recovery Diode ( $t_{rr}$  : 200ns max.)  
           RP1H (SanKen) etc.  
 $C_1, C_2$  : 470µF, 35V (Low Impedance)

$D_{2-4}$  : SBD  $V_{RM} = 60V, I_{FSM} > 60A$  Class  
 $R_1$  : 1Ω, 1W Class  
 $R_2$  : 10Ω, 1/4W Class  
 $D_{Z3-6}$  :  $V_{pn} < \text{Total } V_Z < V_{CES}$  of IGBT  
           Rough guide of total  $V_Z$  is as follows:  
           For  $V_{CES}$  1200V Series → 900-1000V  
           For  $V_{CES}$  1700V Series → 1300-1400V  
           It depends on  $V_{pn}, I_{C(max)}, R_G$ , snubber  
           circuit inductance of power main circuit, and  
           kind of main condenser.

**NOTE:**

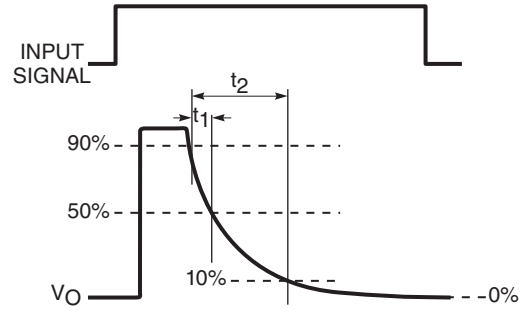
- Decoupling capacitors should be located as close as possible to the Hybrid IC pins.
- The gate circuit path should be kept as short as possible to minimize influence of switching noise.
- $D_1$  requires approximately the same blocking voltage as the IGBT modules.
- When recovery current flows in  $D_1$ , Pin 30 sees high voltage. A zener diode between Pin 21 and Pin 30 is necessary as shown in above diagram.
- To decrease the speed of output fall time (reverse bias) when protection circuit is operating, connect  $C_S$  between Pin 21 and Pin 27.
- If the short-circuit protection circuit is not used, please connect a 4.7k ohm resistor between Pin 30 and Pin 20. ( $D_1$  and  $D_{Z1}$  are not required.)
- If the collector clamp circuit is activated repeatedly, it may be destroyed as a result of overheating. For this reason, power dissipation of the zener diode should be determined by testing in the actual inverter.

**VLA554-01R**  
**IGBT Gate Driver + DC/DC Converter**

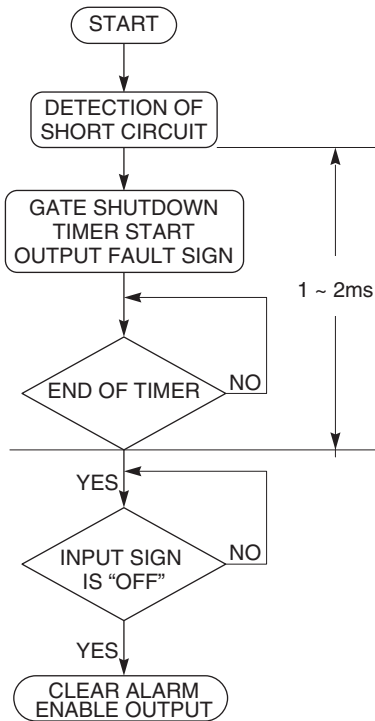
### Operation of Protection Circuit

1. When an "ON" input signal is applied for a period longer than  $T_{trip}$  and the collector voltage is high, the hybrid IC will recognize the condition as a short-circuit and immediately reduce the gate voltage. It will also produce a low voltage fault signal at the respective Pin 28 alerting that the protection circuit is in operation.
2. The protection circuit will reset if an "OFF" input signal is applied and the minimum 1~2ms shutdown time has passed. "OFF" signal must be 15 $\mu$ s or more.
3. The controlled time to detect a short-circuit ( $T_{trip}$ ) should be set so that the IGBT can be fully turned "ON" before a short-circuit condition can be detected. It is possible to adjust  $T_{trip}$  by connecting a capacitor ( $C_{trip}$ ) between Pins 21, 22 and 29.
4. When the short-circuit protection is activated, the soft gate shutdown circuit reduces the collector surge voltage on the IGBT. The gate shut down speed can be slowed even more by adding a capacitor to the CS terminal (between Pins 21, 27).

### Adjustment of Output Fall Time

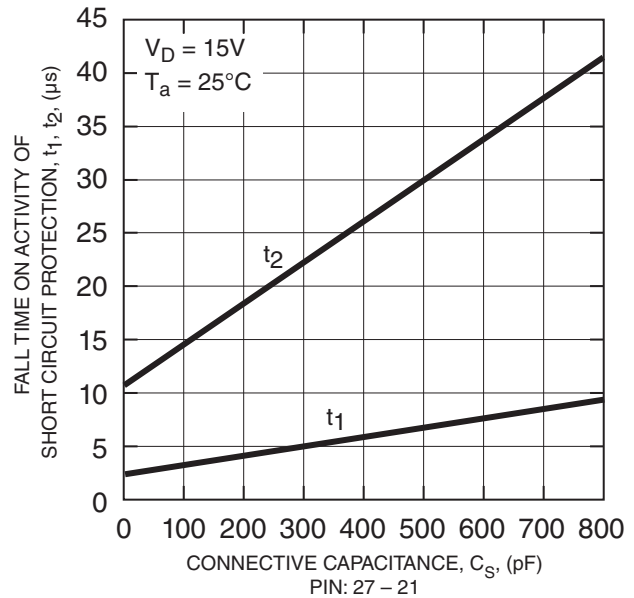


### Operation Flow on Detecting Short Circuit



NOTE: Output voltage with protection circuit operating is about  $-|V_{EE}| + 2V$

**$t_1, t_2$  vs  $C_S$  CHARACTERISTICS (TYPICAL)**



**VLA554-01R**  
**IGBT Gate Driver + DC/DC Converter**

### Capacity for Power Supply on Input Side

This product has an isolated DC-DC converter built in for gate drive. Follow these three steps to determine the proper capacity of the power supply on the input side.

1. Calculate the average gate current.

$$I_{drive} = (Q1 + IQ2) \times F$$

$I_{drive}$  : Gate average current  
 Q1 : Gate charge at +15V (read from IGBT datasheet)  
 Q2 : Gate charge at -7V (read from IGBT datasheet)  
 f : Switching frequency of IGBT

2. Required current from performance curve.

If the result of the calculation for  $I_{drive}$  is 100mA,  $I_D$  is about 270mA as shown on the graph.  
 $I_D$  : Consumption current of DC-DC converter in this HIC

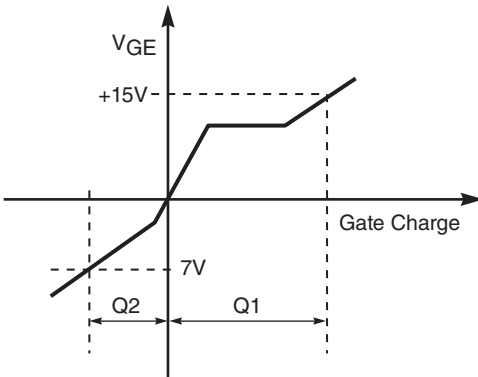
3. Calculate the margin

$$I_{out} = I_D \times (1 + \text{margin})$$

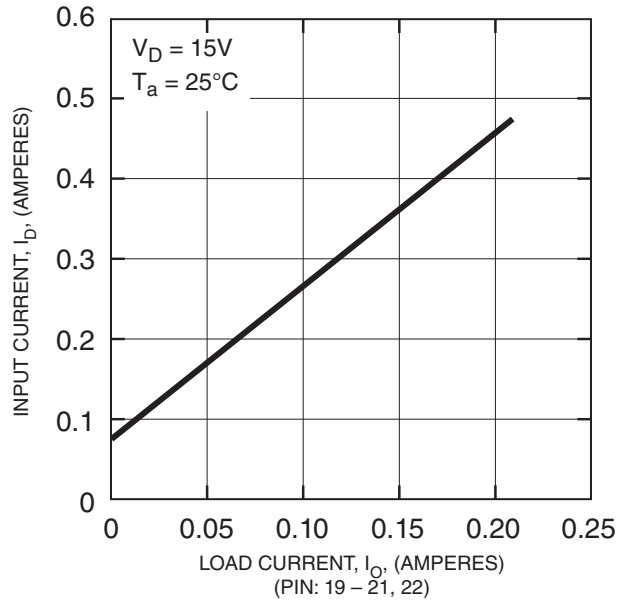
$I_{out}$  : Output current of input power supply  
 Margin : 0.4

If the result of  $I_D$  is 270mA, the power supply spec is:  
 Output voltage : 15V  
 Output current : greater than 350mA

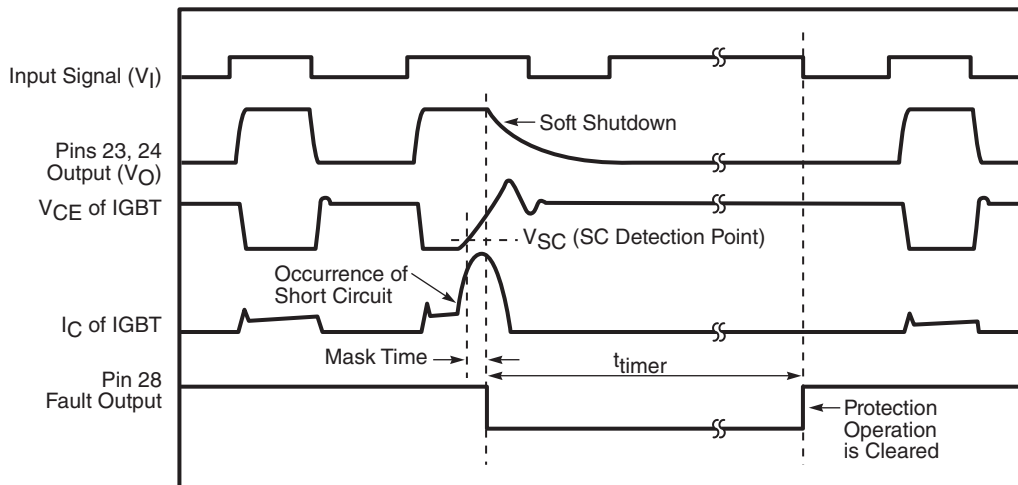
**GATE CHARGE CHARACTERISTICS OF IGBT**



**$I_D - I_O$  CHARACTERISTICS (TYPICAL)**

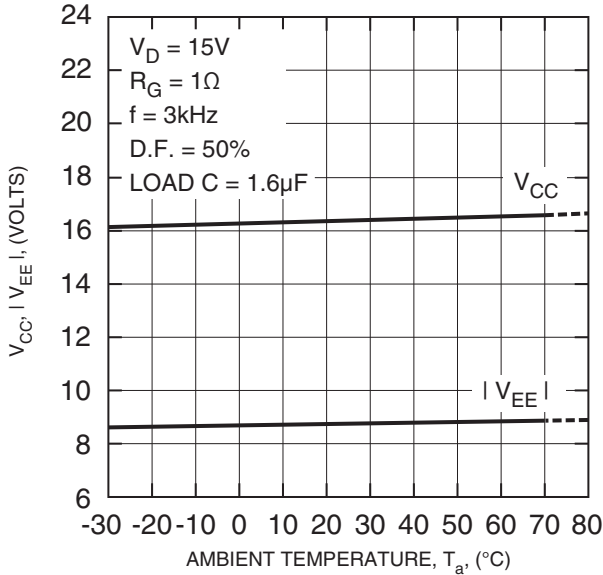


### Timing Chart

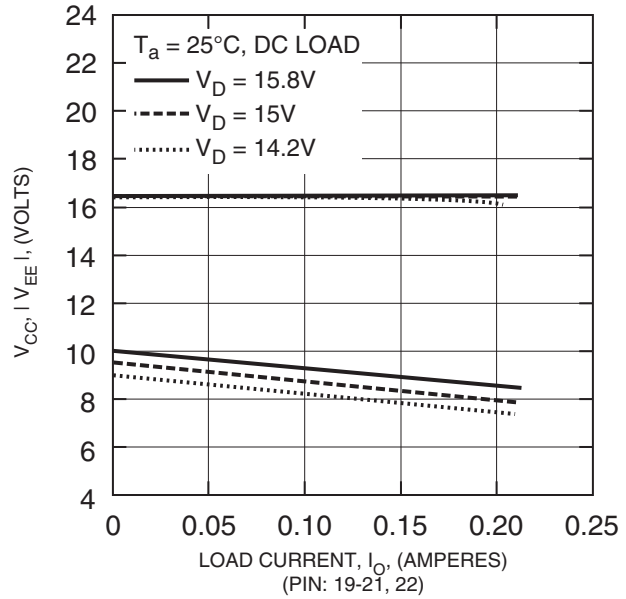


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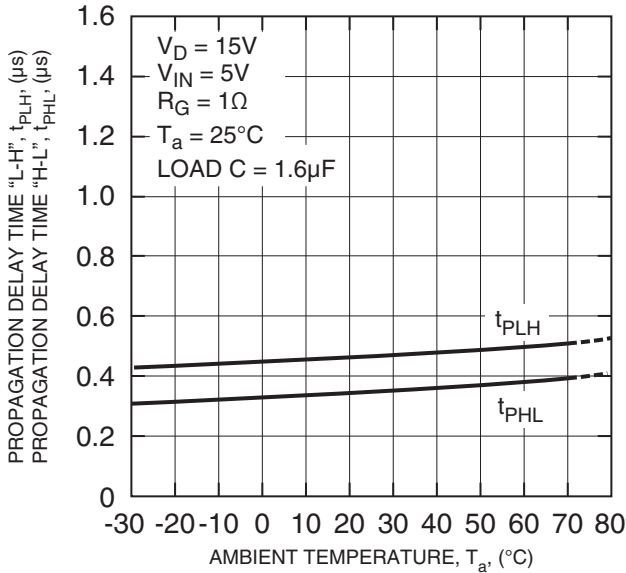
$V_{CC}$ ,  $|V_{EE}|$  -  $T_a$  CHARACTERISTICS (TYPICAL)



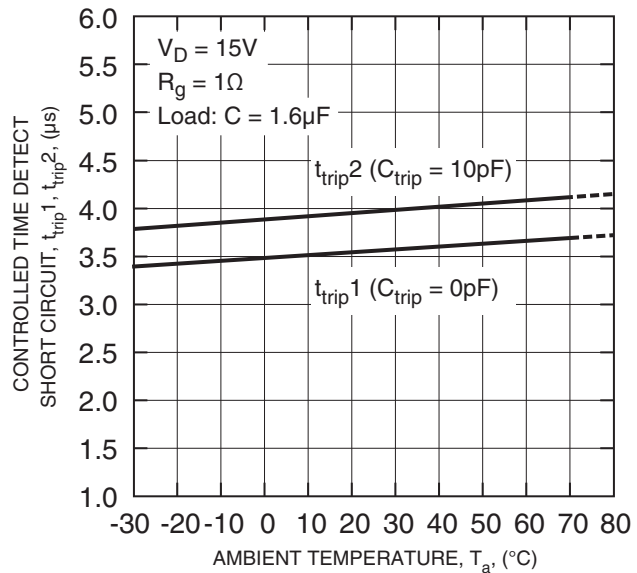
$V_{CC}$ ,  $|V_{EE}|$  -  $I_O$  CHARACTERISTICS (TYPICAL)



$t_{PLH}$ ,  $t_{PHL}$  -  $T_a$  CHARACTERISTICS (TYPICAL)

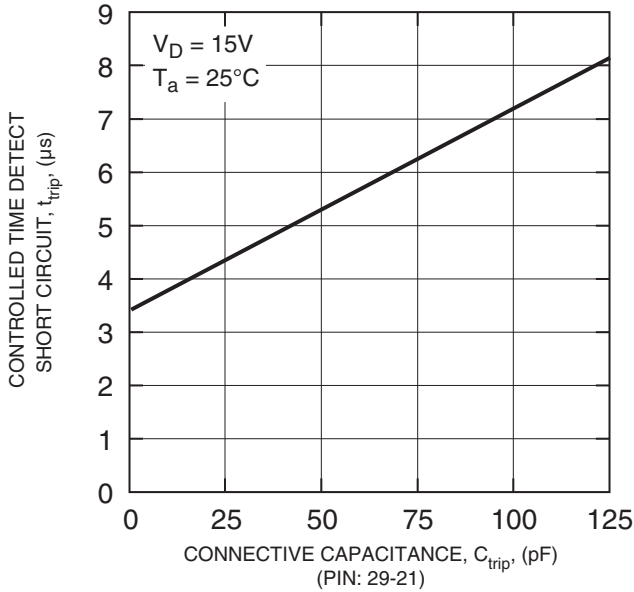


$t_{trip}$  -  $T_a$  CHARACTERISTICS (TYPICAL)

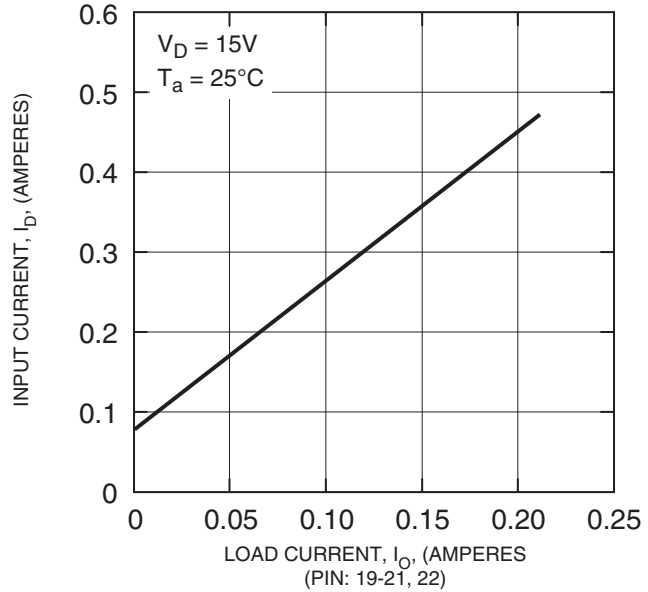


VLA554-01R  
IGBT Gate Driver + DC/DC Converter

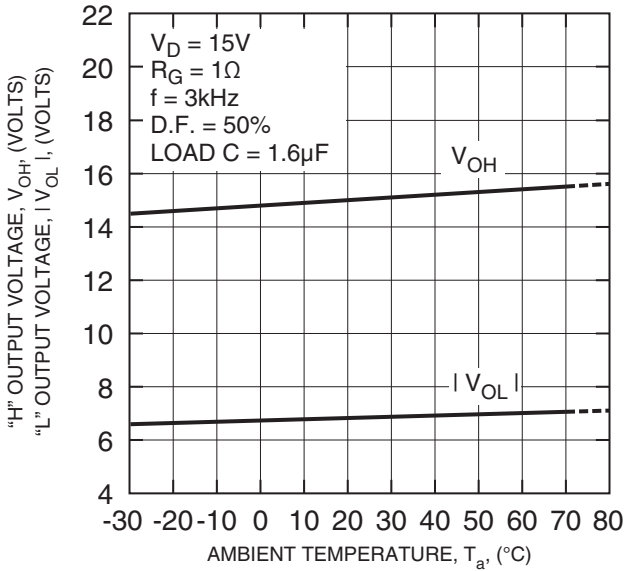
$t_{trip}$ - $C_{trip}$  CHARACTERISTICS  
(TYPICAL)



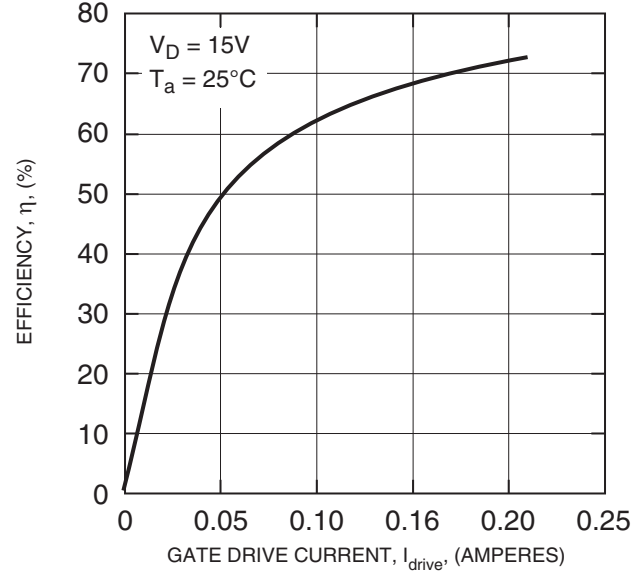
$I_D$ - $I_O$  CHARACTERISTICS  
(TYPICAL)



$V_{OH}$ ,  $|V_{OL}|$  -  $T_a$  CHARACTERISTICS  
(TYPICAL)



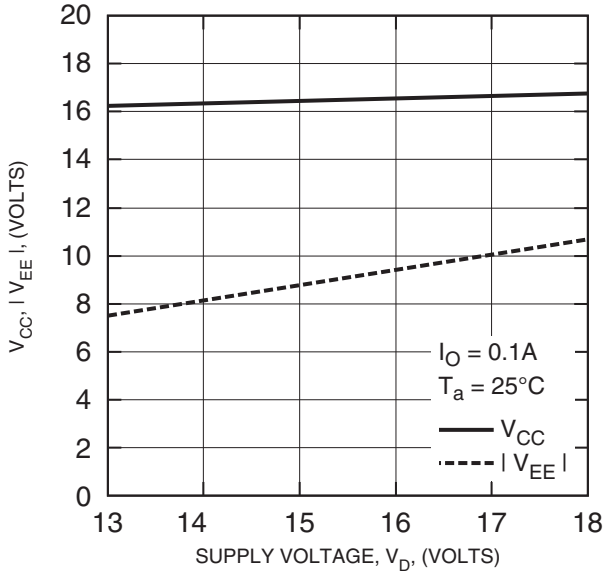
$\eta$ - $I_{drive}$  CHARACTERISTICS  
(TYPICAL)



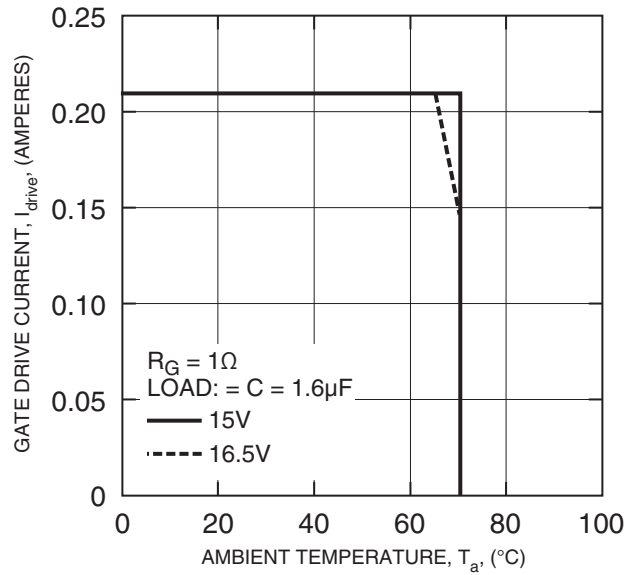


VLA554-01R  
IGBT Gate Driver + DC/DC Converter

$V_{CC}, |V_{EE}|, -V_D$  CHARACTERISTICS  
(TYPICAL)



$I_{drive}-T_a$  CHARACTERISTICS  
(TYPICAL)



$\eta-V_D$  CHARACTERISTICS  
(TYPICAL)

